

**Green Products** 

# **SK520 SCHOTTKY RECTIFIER**

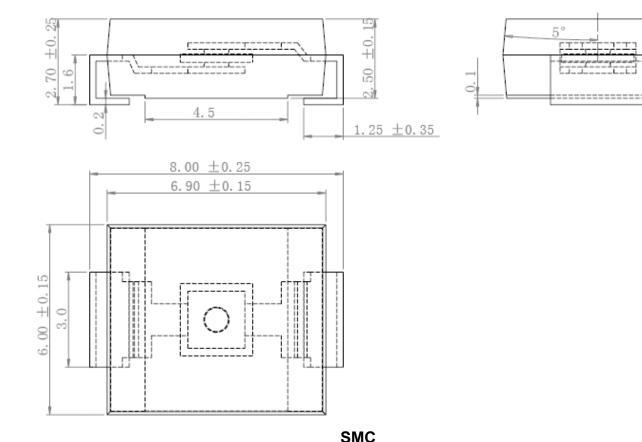
#### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Features:

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Dimensions (In mm / Inches):**



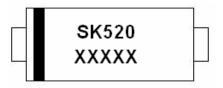
<sup>•</sup> Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 🗏 (86) 25-87123907 •

<sup>•</sup> FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



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## **Marking Diagram:**



Where XXXXX is YYWWL

SK520 = Part Name
 YY = Year
 WW = Week
 L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping
SK520	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

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## Maximum Ratings and Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	SK520	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	200	V
Maximum RMS Voltage	$V_{RMS}$	140	V
Average Rectified Output Current (Note 1)	I <sub>F(AV)</sub>	5.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	120	А
Forward Voltage $@I_F = 5.0A, T_A = 25^{\circ}C$ $@I_F = 5.0A, T_A = 125^{\circ}C$	$V_{FM}$	1.10 0.90	<b>\</b>
	I <sub>RM</sub>	1 7	mA
Typical Thermal Resistance Junction to Ambient	$R_{ heta J^{A}}$	10	°C /W
Storage Temperature Range	$T_{STG}$	-55 to +150	°C
Max. Junction Temperature	$T_J$	-55 to +150	°C
Approximate Weight	wt	0.65	g
Case Style		SMC	

Note:1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

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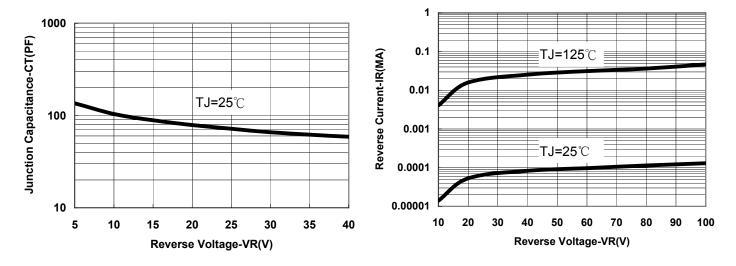


Fig.1-Typical Junction Capacitance Vs.Reverse Voltage

Fig.2-Typical Values Of Reverse Current Vs.Reverse Voltage

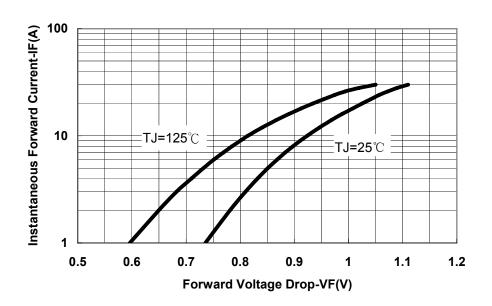


Fig.3-Typical Forward Voltage Drop Characteristics

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MICROELECTRONICS SK520

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Technical Data
Data Sheet N0107, Rev. -

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